Phase noise of an electro-optical phase 2 modulator based electro-optical comb

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Abstract: Photonic millimeter wave and terahertz frequency generation and detection benefit 11 from a large tunability of several octaves as opposed to electronic frequency generation and mul-12 tiplication. However, reaching multiple 100 GHz continuous tuning range while simultaneously 13 featuring a linewidth in the Hz range and low phase noise is still very challenging. We present an 14 electro-optical comb driving a photomixer with potential usability as an extension module based 15 on side-band generation by an electro-optical phase modulator. This enables a Hz-level linewidth 16 from microwaves to terahertz frequencies. We discuss the working principle of the mentioned 17 electro-optical comb, characterize the phase noise of the optical subsystem up to frequencies of 18 40 GHz where electronic phase noise analyzers are available and draw conclusions on the phase 19 noise at higher frequencies in the THz domain. 20

21 1. Introduction

Superheterodyne receivers found many use-cases since their development in the early 20th century 22 [1] including radios, wireless communications, astronomy [2] and being part of measurement 23 equipment i.e. spectrum analysers [3]. These receivers require a local oscillator (LO) providing a 24 LO frequency and a mixer that mixes this frequency with the signal. Typically, mixers are based 25 on diodes or transistors [4] and the LO has to emit at a similar frequency as the signal to be 26 measured. Examples for LOs are voltage controlled oscillators [5], YIG-tuned oscillators [6], 27 crystal oscillators [7] and atomic oscillators with stabilities in the order of and below 10^{-11} per 28 month [8]. With additional synthesizers like phase locked-loops [9] or frequency multipliers 29 based on diodes or transistors [10] these oscillators reach millimeter (mm) wave and terahertz 30 (THz) frequencies. Between 2 THz and 5 THz quantum cascade lasers have been implemented [2]. 31 In general, oscillators are subject to frequency fluctuations. These fluctuations can be translated 32 from frequency to phase and are typically denominated as phase noise [11] which is one of 33 the parameters used to describe the signal purity of the oscillator. Phase noise is a statistical 34 process and therefore the spectral phase noise on both sides of the oscillation frequency is 35 typically the same. Therefore, it is sufficient to measure the single side-band phase noise. A 36 phase noise measurement determines the noise power at offset frequencies from the peak of 37 the oscillation frequency. A low phase noise of electronic oscillators of $-105.72 \, \text{dBc/Hz}$ at 38 1 MHz was demonstrated at a center frequency of 58.48 GHz [12], -107.5 dBc/Hz at 1 MHz at 39 a center frequency close to 20 GHz [13] and $-110 \,\mathrm{dBc/Hz}$ at 10 MHz at a center frequency of 40 176 GHz [14]. In contrast to classical electronic systems, photonic systems use an optical signal, 41 e.g. around 1550 nm (\sim 193 THz), that features at least two frequencies. A photomixer absorbs 42 the laser signal in order to generate the LO frequency -being the difference frequency of these 43 two colors- in form of a charge- or photocurrent modulation. The simplest implementation of this 44 are two free-running continuous-wave (CW) lasers. As these are independent and just thermally 45 stabilized they showcase a typical linewidth in the tens of kHz to the low MHz range [15] and thus 46

large phase noise. The phase noise can be significantly reduced by referencing these two lasers 47 either to themselves, to a high finesse cavity or to a frequency standard [16, 17]. Besides, optical 48 frequency combs are a very low linewidth alternative. Phase noises as low as $-108 \, \text{dBc/Hz}$ 49 at 1 MHz at a center frequency of 560 GHz with a soliton comb [18] and -90 dBc/Hz to 50 -95 dBc/Hz at 10 kHz at center frequencies of 330 GHz, 415 GHz and 500 GHz [19] have been 51 achieved by locking CW lasers to pulsed frequency comb lines. While the first one is hardly 52 tunable, the second one requires many expensive components. 53 In this paper we show that a relatively simple electro-optic (EO) comb also features excellent 54 phase noise. EO combs generate multiple side bands on a single laser signal by EO phase 55 modulation [20]. Originating from the same EO driver signal, the side bands show predominantly 56 common noise such that mixing of any two side bands yields a signal with a spectral purity of the 57 order of the radio frequency (RF) generator used to drive the EO comb. In a previous publication, 58 we have shown that the linewidth is in the 1 Hz range [21], however, we had not analyzed its 59 phase noise spectrum. The EO comb can be tuned by changing the RF or by selecting different 60 side band combinations. We remark that all mentioned comb-based systems can reach THz 61 frequencies [22, 23]. With the lack of a sufficient THz spectrum analyzer, we analyze the phase 62 noise in this paper at 40 GHz where electronic measurement equipment is available. Section 63 2 discusses the difference frequency generation (DFG), section 3 estimates the phase noise 64 contributions and section 4 showcases phase noise measurements under different settings with 65 comparisons to the theory. 66

67 2. Electro-optical comb generation

For all of the considerations and measurements a fiber-coupled telecom-wavelength EO comb
 like the one presented in fig. 1 is used. This setup resembles a Mach-Zehnder interferometer [24].



Fig. 1. Difference frequency generation setup with electro-optical phase modulator (EOM) -based EO comb. The Rubidium clock is optional. (CW - continuous-wave, PC - polarisation controller, EDFA - erbium doped fiber amplifier, VODL - variable optical delay line, Rb - Rubidium)

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The continuous-wave (CW) laser generates a 1550 nm signal with an electrical field strength $E_{\rm L}(t)$ of $E_{\rm L}(t) = E_0 e^{j \omega_{\rm L} t}$, where E_0 is the amplitude of the electric field and $\omega_{\rm L}$ the laser frequency. A subsequent 3-dB coupler splits the signal in two paths. The upper path contains an electro-optical phase modulator (EOM), a tunable optical filter and an erbium-doped fiber

amplifier (EDFA). The EOM is driven by an amplified radio frequency (RF) generator producing

⁷⁶ a sinusoidal signal with an angular frequency $\omega_{\rm RF}$. Thus, the EOM modulates the phase of the ⁷⁷ laser signal as

$$E_{\text{EOM}}(t) = \frac{E_0}{\sqrt{2}} \eta_{\text{EOM}} e^{j(\omega_{\text{L}}t + \gamma \sin(\omega_{\text{RF}}t))} = \frac{E_0}{\sqrt{2}} \eta_{\text{EOM}} \sum_{k=-\infty}^{\infty} J_k(\gamma) e^{j(\omega_{\text{L}}+jk\omega_{\text{RF}})t}$$
(1)

where η_{EOM} is the optical insertion loss of the EOM and γ is the modulation depth given with

$$\gamma = \frac{\pi V_0}{V_\pi(\omega_{\rm RF})} \tag{2}$$

with the voltage applied to the EOM V_0 and its half-wave voltage V_{π} . The Jacobi-Anger 79 expansion [25] at the right hand side of (1) shows that a sinusoidal modulated phase results in 80 generation of side bands with a spacing of $\omega_{\rm RF}$ whose strength decays with the kth order Bessel 81 function of the first kind, $J_k(\gamma)$. The modulation factor determines the strength of the different 82 frequency components. A high modulation factor therefore generates more power in higher 83 modes. η_{EOM} summarizes the optical losses within the EOM. The optical filter with an insertion 84 loss at the pass band of $\eta_{\rm F}$ selects a single mode m. The EDFA with a gain of G_1 compensates 85 for the losses by the components in the upper path, leading to a field of 86

$$E_{\rm F}(t) = \frac{E_0}{\sqrt{2}} G_1 \eta_{\rm EOM} \eta_{\rm F} J_m(\gamma) e^{j(\omega_{\rm L} + m\omega_{\rm RF})t}$$
(3)

In order to effectively cancel common noise in mixing the frequencies in the top and bottom path, both paths must be mutually coherent, i.e. their path length difference must be (much) smaller than the coherence length of the CW laser. Therefore, the bottom path only contains fiber including variable optical delay lines (VODL) with a total length compensating for the accumulated fiber lengths, yet with a small remaining phase difference $\Delta\varphi$ between the two. After combining both paths an additional EDFA with gain G_2 matches the power with the input requirements of the subsequent photomixer that now receives a heterodyned signal of

$$E_{\rm comb}(t) = \frac{E_0 G_2}{\sqrt{2}} \left[\eta_{\rm EOM} \eta_{\rm F} J_m(\gamma) G_1 e^{j(\omega_{\rm L} + m\omega_{\rm RF})t} + e^{j(\omega_{\rm L} t + \Delta\varphi)} \right].$$
(4)

The photomixer (either a photoconductor in the case of a photonic spectrum analyzer [15,21] or a p-i-n- diode as used in this paper) absorbs the laser signal resulting in a DC and AC charge carrier modulation, σ , that follows the optical beat note and acts as local oscillator,

$$\sigma \sim \left(\sigma_1 + \sigma_2 + 2\sqrt{\sigma_1 \sigma_2} \cos\left(m\omega_{\rm RF}t + \Delta\varphi\right)\right) \tag{5}$$

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with
$$\sigma_1 = \eta_{\text{PM}} \left(\frac{E_0}{\sqrt{2}} \eta_{\text{EOM}} \eta_{\text{Filter}} G_1 G_2 J_m(\gamma) \right)^2$$
 and $\sigma_2 = \eta_{\text{PM}} \left(\frac{E_0}{2} G_2 \right)^2$, (6)

where c_0 is the speed of light, ϵ_0 the vacuum permittivity and η_{PM} is the photomixer's conversion efficiency. Maximising the THz component at $m\omega_{RF}$ requires $\sigma_1 = \sigma_2$, hence $G_1 = (\eta_{EOM}\eta_{Filter})^{-1}$. η_{PM} is sensitive to the polarisation of the EO comb lines. As some components are non-polarization maintaining, we implement polarisation controllers (PC).

3. Phase noise considerations

¹⁰³ In the following, we assume the phase noise contributions of the individual system components ¹⁰⁴ as independent although the statistical description of phase noise is non-trivial and there may be

minor inter-dependencies [11,26]. The top path experiences phase noise from the laser, ϕ_L , the 105 RF generator with amplifier and the EOM, summarized as $\phi_{\rm RF}$, and both EDFAs, $\phi_{\rm EDFA,i}$ while 106 the bottom path is only affected by the laser and the second EDFA. We remark that the filter may 107 indeed reduce noise as it suppresses out-of-band noise. The passband width of optical filters, 108 however, is typically at least a few GHz wide and thus about 3 orders of magnitude wider than 109 the frequency range typically investigated around the main peak in phase noise measurements. 110 We therefore disregard effects of the optical filter on noise. The laser phase noise in both paths 111 are correlated but may not completely cancel out for imperfect path length compensation. In the 112 following, we express the relative time delay caused by the path length difference between the 113 two paths as τ . The instantaneous phases for both frequency components become 114

$$\phi_1(t) = \phi_{\rm L}(t) + |m|\phi_{\rm RF}(t) + \phi_{\rm EDFA1}(t) + \phi_{\rm EDFA2}(t)$$
(7)

$$\phi_2(t) = \phi_{\rm L}(t-\tau) + \phi_{\rm EDFA2}(t) \tag{8}$$

As the photoconductor generates the difference frequency signal, only phase differences survive, leading to a LO phase of

$$\phi_{\rm DF}(t) = \phi_{\rm L}(t) - \phi_{\rm L}(t-\tau) + |m|\phi_{\rm RF}(t) + \phi_{\rm EDFA1}(t).$$
(9)

We remark that the frequencies in both paths are slightly different which may, in principle, 117 lead to different phase noise in common components, e.g. in EDFA2, as its noise floor is 118 wavelength-dependent. For THz generation, the two tones are considerably close and we therefore 119 omit non-common phase noise originating from EDFA2. Due to wavelength-dependent gain. 120 there may be excess amplitude noise. In addition to the aforementioned noise sources the 121 photomixer (photoconductor or p-i-n diode) attached to the EO comb adds thermal noise caused 122 by its resistance which is predominantly white. The photocurrent noise floor of photoconductors 123 measured in Terahertz homodyne systems is in the range of a few pA \sqrt{Hz} at an illuminated 124 resistance in the range of 5 k $\omega_{\rm RF}$ to 50 k $\omega_{\rm RF}$. The resulting noise spectral density should therefore 125 be (much) smaller than the noise sources addressed in this manuscript. The phase noise, resulting 126 from fluctuations of the phase in 9, is typically measured at the single side-band (SSB) in the 127 frequency domain, $L(f) \sim (\phi_{\rm DF}(f))^2$. Its power spectral density is 128

$$L_{\rm DF}(f) = |m|^2 L_{\rm RF}(f) + L_{\rm EDFA1}(f) + L_{\rm L}(f,\tau) + L_{\rm PCA}(f) = |m|^2 L_{\rm RF}(f) + L_{\rm opt}(f), \quad (10)$$

where $L_{PCA}(f)$ accounts for the photoconductor noise. From Eq. 10 we can draw two conclusions: 129 (i) For perfect path length compensation, i.e. $\tau = 0$, the phase of the laser, including its noise 130 contribution, perfectly cancels. The predominant noise source in this case is the RF system whose 131 noise is typically orders of magnitude smaller than that of the free running CW laser. If τ becomes 132 much larger than the coherence time of the CW laser then the phases in both paths become 133 uncorrelated and will just add up, resulting in twice the laser's phase noise. Therefore, the path 134 lengths have to be matched. For free running lasers, the coherence length is of the order of several 135 meters, so a minor (almost inevitable) mismatch of pathlengths in the cm range can be tolerated. 136 (ii) As the RF $\omega_{\rm RF}$ is tunable and the system permits to pick any side mode order m, any LO 137 frequency $f_{\rm LO} = m\omega_{\rm RF}/(2\pi)$ can be generated in several ways (e.g. m' = 2m and $\omega'_{\rm RF} = \omega_{\rm RF}/2$). 138 The phase noise of the RF generator typically scales quadratically with the operation frequency. 139 Yet, as Eq. 10 consists of an RF noise contribution that scales with the square of the side 140 band order but noise originating from optical components and the photoconductor that remains 141 independent of the side mode order, we expect a sub-quadratic increase of noise with side mode 142 order. 143

144 4. Phase noise analysis of the photonic LO

The EO comb system consists of the following components: a distributed feedback laser diode
 Profile WDM source at 1542.88 nm emitting an optical power of 13 dBm, an EOSpace PM-OS5-

20-PFA-PFA EOM, a Rohde & Schwarz SMP02 RF generator, referenced to a 10 MHz Rubidium 147 (Rb) clock (Rohde & Schwarz XSRM with XSRM-Z), a HP8349B RF amplifier, a Yenista Optics 148 XTA-50 tunable filter with the filter bandwidth set to 50 pm, an Amoco Laser Company L5-Amp 149 as EDFA1, and a Pritel, Inc. optical fiber amplifier PMFA-35-S-10 as EDFA2. The bottom path 150 contains two VODLs (OZ Optics ODL-650-11-1550-8/125-P-60-3A3A-1-1-MC/RS232-330). 151 The output power of the RF generator is set to 10 dBm resulting in a total output power between 152 20 dBm and 27 dBm after the RF amplifier. Except the optical filter and EDFA1 all of components 153 and fibers are polarisation maintaining. The polarisation is monitored at the second output of 154 the polarizing beam splitter with a Sainsonic OP-600 optical power meter. By adjusting both 155 PCs the undesired polarisation was suppressed to values below $-10 \, \text{dBm}$ for all measurements. 156 i.e. resulting in a polarisation suppression of at least 95 %. In order to analyze the phase noise of 157 the photonic LO, we connect a fast photodiode (u^2t XPDV2120R) to the EO comb followed by a 158 low noise amplifier (MiniCircuits ZVA-403 GX+). Its output is fed to a RF phase noise analyser 159 (Rohde & Schwarz FWSP). To check the optical output power of the EO comb an inline optical 160 power meter (Neo Photonics) is placed in between the output of the EO comb and the photodiode. 161 Table 1 summarizes the settings of the EO comb devices. We chose to use the sidebands above 162 the centre wavelength of the laser with the filter. Please note that the calibration of the centre 163 wavelength of the optical filter has a systematic offset error of up to 200 pm. The power of the 164 EDFA1 is set to match the power of the selected mode with the power at the laser wavelength in 165 the bottom path. Its setting ranges from 0 to 1 and scale with its current. The output power of 166 EDFA2 is 10 dBm.

Difference	RF	Optical	Optical filter	EDFA1 power
frequency	frequency	mode	centre wavelength	setting
10 GHz	10 GHz	1	1542.917 nm	0.163
20 GHz	10 GHz	2	1543.004 nm	0.142
30 GHz	10 GHz	3	1543.085 nm	0.168
40 GHz	10 GHz	4	1543.167 nm	0.214
40 GHz	13.3 GHz	3	1543.155 nm	0.200
20 GHz	20 GHz	1	1543.003 nm	0.147
40 GHz	20 GHz	2	1543.155 nm	0.203

Table 1. Measurement settings for the showcased difference frequencies.

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168 4.1. Fiber compensation length

In a first step, we optimized the compensation fiber length in the bottom path. From preliminary 169 work we estimate the combined fiber length of the EOM, optical fiber, EDFA1 and PC to about 170 (33.6 ± 0.1) m. Fig. 2 shows the resulting phase noise at fiber compensation lengths from 171 31.11 m to 35.45 m. We state an absolute error of at least 5 cm as the length of the VODLs is 172 only estimated from its size and time delay setting and the lengths of the used fibers may vary 173 slightly from their stated length. The increase of phase noise due to remaining laser noise is 174 evident. The lengths between 33.51 m and 33.65 m show the lowest phase noise. Between these 175 lengths the phase noise difference is smaller than the run-to-run deviation. In the following, we 176 used the mean between these two values, i.e. 33.57 m. The phase noise difference of the longer 177 compensation fiber lengths increases confirming imperfect noise cancelling of the correlated 178

¹⁷⁹ laser phase noise at large values of τ .



Fig. 2. Measured phase noise for different compensation fiber lengths at a difference frequency of 40 GHz using the second optical mode.

180 4.2. Referencing and amplitude noise

For all of the following measurements the phase noise is acquired from 1 Hz to 1 MHz with a 181 resolution bandwidth of 5 % and a cross-correlation factor of 100. Fig. 3 contains the results of 182 measurements of the RF generator at 20 GHz with and without referencing to the Rb reference 183 clock. These measurements are within run-to-run deviation for offset frequencies above 15 Hz 184 with a phase noise of $-114.9 \, \text{dBc/Hz}$ at 1 MHz. For frequencies below 15 Hz the phase noise of 185 the referenced RF generator is up to 13 dB better. The measurements of the EO comb at 40 GHz 186 using the second mode show the same behaviour with and without reference and reach a phase 187 noise of -108.7 dBc/Hz at 1 MHz. Fig. 3 additionally contains the amplitude noise of the EO 188 comb at 40 GHz using the second mode. The amplitude noise is at least 10 dB and typically 189 25 dB smaller than the phase noise throughout the spectrum. Amplitude noise will therefore be 190 neglected in the following. We conclude that referencing to the Rb clock only impacts the phase 191 noise below ~ 100 Hz. We still employ it for all of the following measurements. 192

¹⁹³ 4.3. Side mode scaling of the phase noise

We compare the scaling of the phase noise at an RF of 10 GHz between the modes one to four. Fig.
4 a) shows the difference between the phase noises from modes two to four compared to mode one.
The noise contributions show substantial differences depending on the offset frequency. In the
high frequency end, above 13 kHz, the noise scales almost exactly quadratically. For convenience
we added horizontal lines corresponding to exact quadratic scaling. Fig. 4 b) depicts the average



Fig. 3. Measured phase noise of the RF generator at 20 GHz and the EO comb at 40 GHz, both with and without referencing to the Rb clock. Additionally, the EO comb at 20 GHz and the amplitude noise at 40 GHz is shown.

noise between 15 kHz and 1 MHz with a maximum deviation of 0.5 dB from quadratic scaling. 199 $L_{\rm RF}(f)$ dominates the phase noise in this part of the noise spectrum. For offset frequencies 200 between 100 Hz and 4 kHz external noise sources dominate the spectral noise and possibly some 201 minor contributions from $L_{opt}(f)$ as the phase noise shows hardly any dependency on the mode 202 order. Some of this phase noise is generated by the fans of the devices, other acoustic sources 203 and potentially vibration. The phase noise differences between 5 Hz and 100 Hz show mode 204 dependent but sub-quadratic behaviour. This is caused when the phase noise of both $L_{RF}(f)$ and 205 $L_{\text{opt}}(f)$ are similar in size. Together with the findings from Fig. 3 we conclude that the dominant 206 noise source is the phase noise of the RF generator, except between 100 Hz and 4 kHz. If even 207 higher optical modes than shown here are used, $|m|^2 L_{\rm RF}(f)$ will eventually become the main 208 contributor to the phase noise and we expect purely quadratic scaling. 209

210 4.4. Combined scaling

A difference frequency of 40 GHz can be achieved by a multitude of RF and mode combinations (Tab. 1). Fig. 5 shows the resulting phase noises for the modes two to four. The phase noises have a typical difference of less than 1 dB. Larger differences of up to 4 dB occur at 575 Hz, close to 1 Hz, and above 500 kHz. All three phase noises are basically the same. In the end, only the total multiplication factor matters, irrespective of whether multiplication ocurred in the RF domain or as higher EO side band order.



Fig. 4. a) Differences of the measured phase noise of the modes 2 to 4 compared to the mode 1 using a RF of 10 GHz with solid black lines for the corresponding fully quadratic scalings, b) scaling of the noise with mode number for different spectral ranges with a black line representing fully quadratic scaling.

217 5. Conclusion

We investigated the phase noise of an electro-optical comb for photonic millimeter wave and 218 terahertz generation. We have proven a competitive phase noise of $-108.7 \, \text{dBc/Hz}$ at an offset 219 frequency of 1 MHz at a center frequency of 40 GHz. For low offset frequencies, the phase noise 220 scales sub-quadratically with the electro-optical mode but approaches a quadratic scaling for 221 offset frequencies above ~ 15 kHz. The phase noise of the generated millimeter-wave or THz 222 frequency is mainly determined by the phase noise of the driving RF generator plus 6dB for 223 each time the RF is electro-optically multiplied by a factor of 2. In that context, it does not 224 make a difference whether this multiplication is happening in the optical domain by using higher 225 order modes or in the RF domain. Except for a small window between 100 Hz and a few kHz 226 where the phase noise was dominated by external sources the noise of the spectral purity and 227 stability of the radio frequency generator limits the phase noise performance. An RF generator 228 with a lower phase noise would immediately reduce the millimeter wave and Terahertz phase 229 noise. We remark that locking to a Rubidium clock only affected offset frequency components 230 below $\sim 100 \, \text{Hz}$. The proposed EO comb system is well suited as an extension module for 231 electronic measurement equipment. We remark that higher frequencies deep into the THz range 232 had already been demonstrated with EO combs in the literature. The maximum frequency of 233 40 GHz investigated in this manuscript was solely dictated by the frequency coverage of the phase 234 noise analyzer. 235



Fig. 5. Measured phase noise of the EO comb at 40 GHz, generated with different EO modes.

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296 Appendix A: Correlated phase noise

- 297 SSB phase noise L(f) is proportional to the square phase fluctuation $\phi(f)$. Translating it to the
- ²⁹⁸ time domain leads to

$$\mathcal{F}^{-1}((\phi(f))^2) = \phi(t) * \phi(t) = \int_{-\infty}^{\infty} \phi(t')\phi(t-t')dt'$$

In case of correlated noise $\phi(t) = \phi_c(t) - \phi_c(t - \tau)$ leading to

$$\mathcal{F}^{-1}((\phi_{c}(f))^{2}) = [\phi_{c}(t) - \phi_{c}(t-\tau)] * [\phi_{c}(t) - \phi_{c}(t-\tau)]$$
$$= \int_{-\infty}^{\infty} [\phi_{c}(t') - \phi_{c}(t'-\tau)] [\phi_{c}(t-t') - \phi_{c}(t-t'-\tau)] dt'$$
$$= \int_{-\infty}^{\infty} \phi_{c}(t') - \phi_{c}(t-t') dt' - \int_{-\infty}^{\infty} \phi_{c}(t') - \phi_{c}(t-t'-\tau) dt'$$
$$- \int_{-\infty}^{\infty} \phi_{c}(t'-\tau) - \phi_{c}(t-t') dt' + \int_{-\infty}^{\infty} \phi_{c}(t'-\tau) - \phi_{c}(t-t'-\tau) dt'$$

300 If $\tau = 0$, then

$$\mathcal{F}^{-1}((\phi_{c}(f))^{2})|_{\tau=0} = \int_{-\infty}^{\infty} \phi_{c}(t') - \phi_{c}(t-t')dt' - \int_{-\infty}^{\infty} \phi_{c}(t') - \phi_{c}(t-t')dt' - \int_{-\infty}^{\infty} \phi_{c}(t') - \phi_{c}(t-t')dt' + \int_{-\infty}^{\infty} \phi_{c}(t') - \phi_{c}(t-t')dt' = 0$$

and if τ is significantly larger than the coherence time of the laser, then the two components of the correlated noise can be seen as independent components and sum to $2(\phi(f))^2$.